Elements of X-RAY DIFFRACTION

SECOND EDITION

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A1-1 INTRODUCTION

All the diffraction phenomena described in this book have been discussed in terms of the Bragg law. This simple law, admirable for its very simplicity, is in fact applicable to a very wide range of phenomena and is all that is needed for an understanding of a great many applications of x-ray diffraction. Yet there are diffraction effects which the Bragg law is totally unable to explain, notably those involving diffuse scattering at non-Bragg angles, and these effects demand a more general theory of diffraction for their explanation. The reciprocal lattice provides the framework for such a theory. This powerful concept was introduced into the field of diffraction by the German physicist Ewald in 1921 and has since become an indispensable tool in the solution of many problems.

Although the reciprocal lattice may at first appear rather abstract or artificial, the time spent in grasping its essential features is time well spent, because the reciprocal-lattice theory of diffraction, being general, is applicable to all diffraction phenomena from the simplest to the most intricate. Familiarity with the reciprocal lattice will therefore not only provide the student with the necessary key to complex diffraction effects but will deepen his understanding of even the simplest.

A1-2 VECTOR MULTIPLICATION

Since the reciprocal lattice is best formulated in terms of vectors, we shall first review a few theorems of vector algebra, namely, those involving the multiplication of vector quantities.

The scalar product (or dot product) of two vectors* \mathbf{a} and \mathbf{b} , written $\mathbf{a} \cdot \mathbf{b}$, is a scalar quantity equal in magnitude to the product of the absolute values of the two vectors and the cosine of the angle α between them, or

$$\mathbf{a} \cdot \mathbf{b} = ab \cos \alpha$$
.

Geometrically, Fig. A1-1 shows that the scalar product of two vectors may be regarded as the product of the length of one vector and the projection of the other upon the first. If one of the vectors, say **a**, is a unit vector (a vector of unit length), then **a** · **b** gives immediately the length of the projection of **b** on **a**. The scalar product of sums or differences of vectors is formed simply by term-by-term multiplication:

$$(\mathbf{a} + \mathbf{b}) \cdot (\mathbf{c} - \mathbf{d}) = (\mathbf{a} \cdot \mathbf{c}) - (\mathbf{a} \cdot \mathbf{d}) + (\mathbf{b} \cdot \mathbf{c}) - (\mathbf{b} \cdot \mathbf{d}).$$

^{*} Bold-face symbols stand for vectors. The same symbol in italic stands for the absolute value of the vector.

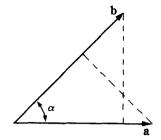


Fig. A1-1 Scalar product of two vectors.

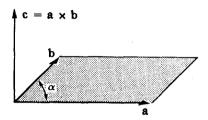


Fig. A1-2 Vector product of two vectors.

The order of multiplication is of no importance; i.e.,

$$\mathbf{a} \cdot \mathbf{b} = \mathbf{b} \cdot \mathbf{a}$$
.

The vector product (or cross product) of two vectors \mathbf{a} and \mathbf{b} , written $\mathbf{a} \times \mathbf{b}$, is a vector \mathbf{c} at right angles to the plane of \mathbf{a} and \mathbf{b} , and equal in magnitude to the product of the absolute values of the two vectors and the sine of the angle α between them, or

$$\mathbf{c} = \mathbf{a} \times \mathbf{b},$$
 $c = ab \sin \alpha,$

The magnitude of c is simply the area of the parallelogram constructed on a and b, as suggested by Fig. A1-2. The direction of c is that in which a right-hand screw would move if rotated in such a way as to bring a into b. It follows from this that the direction of the vector product c is reversed if the order of multiplication is reversed, or that

$$\mathbf{a} \times \mathbf{b} = -(\mathbf{b} \times \mathbf{a}).$$

A1-3 THE RECIPROCAL LATTICE

Corresponding to any crystal lattice, we can construct a reciprocal lattice, so called because many of its properties are reciprocal to those of the crystal lattice. Let the crystal lattice have a unit cell defined by the vectors \mathbf{a}_1 , \mathbf{a}_2 , and \mathbf{a}_3 . Then the

corresponding reciprocal lattice has a unit cell defined by the vectors \mathbf{b}_1 , \mathbf{b}_2 , and \mathbf{b}_3 , where

$$\mathbf{b}_1 = \frac{1}{V} (\mathbf{a}_2 \times \mathbf{a}_3), \tag{1}$$

$$\mathbf{b}_2 = \frac{1}{V} (\mathbf{a}_3 \times \mathbf{a}_1), \tag{2}$$

$$\mathbf{b}_3 = \frac{1}{V} (\mathbf{a}_1 \times \mathbf{a}_2), \tag{3}$$

and V is the volume of the crystal unit cell. This way of defining the vectors $\mathbf{b_1}$, $\mathbf{b_2}$, $\mathbf{b_3}$ in terms of the vectors $\mathbf{a_1}$, $\mathbf{a_2}$, $\mathbf{a_3}$ gives the reciprocal lattice certain useful properties which we will now investigate.

Consider the general triclinic unit cell shown in Fig. A1-3. The reciprocallattice axis b_3 is, according to Eq. (3), normal to the plane of a_1 and a_2 , as shown. Its length is given by

$$b_3 = \frac{|\mathbf{a}_1 \times \mathbf{a}_2|}{V}$$

$$= \frac{\text{(area of parallelogram } OACB)}{\text{(area of parallelogram } OACB)\text{(height of cell)}}$$

$$= \frac{1}{OP} = \frac{1}{d_{001}},$$

since OP, the projection of \mathbf{a}_3 on \mathbf{b}_3 , is equal to the height of the cell, which in turn is simply the spacing d of the (001) planes of the crystal lattice. Similarly, we find that the reciprocal lattice axes \mathbf{b}_1 and \mathbf{b}_2 are normal to the (100) and (010) planes, respectively, of the crystal lattice, and are equal in length to the reciprocals of the spacings of these planes.

By extension, similar relations are found for all the planes of the crystal lattice. The whole reciprocal lattice is built up by repeated translations of the unit cell by the vectors \mathbf{b}_1 , \mathbf{b}_2 , \mathbf{b}_3 . This produces an array of points each of which is labeled with its coordinates in terms of the basic vectors. Thus, the point at the end of the

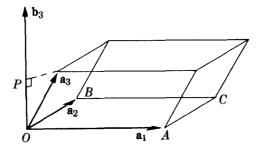


Fig. A1-3 Location of the reciprocal-lattice axis b_3 .

 \mathbf{b}_1 vector is labeled 100, that at the end of the \mathbf{b}_2 vector 010, etc. This extended reciprocal lattice has the following properties:

1. A vector \mathbf{H}_{hkl} drawn from the origin of the reciprocal lattice to any point in it having coordinates hkl is perpendicular to the plane in the crystal lattice whose Miller indices are hkl. This vector is given in terms of its coordinates by the expression

$$\mathbf{H}_{hkl} = h\mathbf{b}_1 + k\mathbf{b}_2 + l\mathbf{b}_3.$$

2. The length of the vector \mathbf{H}_{hkl} is equal to the reciprocal of the spacing d of the (hkl) planes, or

$$H_{hkl}=\frac{1}{d_{hkl}}.$$

The important thing to note about these relations is that the reciprocal-lattice array of points completely describes the crystal, in the sense that each reciprocal-lattice point is related to a set of planes in the crystal and represents the orientation and spacing of that set of planes.

Before proving these general relations, we might consider particular examples of the reciprocal lattice as shown in Figs. A1-4 and A1-5 for cubic and hexagonal crystals. In each case, the reciprocal lattice is drawn from any convenient origin, not necessarily that of the crystal lattice, and to any convenient scale of reciprocal angstroms. Note that Eqs. (1) through (3) take on a very simple form for any crystal whose unit cell is based on mutually perpendicular vectors, i.e., cubic, tetragonal, or orthorhombic. For such crystals, $\mathbf{b_1}$, $\mathbf{b_2}$, and $\mathbf{b_3}$ are parallel, respectively, to $\mathbf{a_1}$, $\mathbf{a_2}$, and $\mathbf{a_3}$, while b_1 , b_2 , and b_3 are simply the reciprocals of a_1 , a_2 , and a_3 . In Figs. A1-4 and A1-5, four cells of the reciprocal lattice are shown, together with two H vectors in each case. By means of the scales shown, it may be verified that each H vector is equal in length to the reciprocal of the spacing of the corresponding planes and normal to them. Note that reciprocal lattice points such as

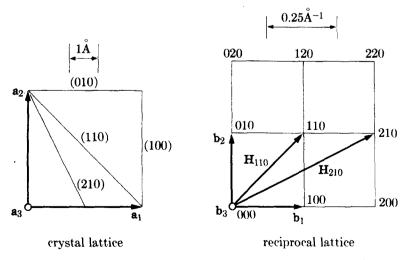


Fig. A1-4 The reciprocal lattice of a cubic crystal which has $a_1 = 4$ Å. The axes a_3 and b_3 are normal to the drawing.

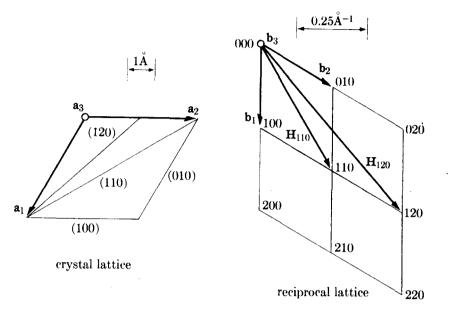


Fig. A1-5 The reciprocal lattice of a hexagonal crystal which has $a_1 = 4$ Å. (Here the three-symbol system of plane indexing is used and a_3 is the axis usually designated c.) The axes a_3 and b_3 are normal to the drawing.

nh, nk, nl, where n is an integer, correspond to planes parallel to (hkl) and having 1/n their spacing. Thus, \mathbf{H}_{220} is perpendicular to (220) planes and therefore parallel to \mathbf{H}_{110} , since (110) and (220) are parallel, but \mathbf{H}_{220} is twice as long as \mathbf{H}_{110} since the (220) planes have half the spacing of the (110) planes.

Other useful relations between the crystal and reciprocal vectors follow from Eqs. (1) through (3). Since \mathbf{b}_3 , for example, is normal to both \mathbf{a}_1 and \mathbf{a}_2 , its dot product with either one of these vectors is zero, or

$$\mathbf{b}_3 \cdot \mathbf{a}_1 = \mathbf{b}_3 \cdot \mathbf{a}_2 = 0.$$

The dot product of b_3 and a_3 , however, is unity, since (see Fig. A1-3)

$$\mathbf{b}_3 \cdot \mathbf{a}_3 = (b_3)$$
 (projection of \mathbf{a}_3 on \mathbf{b}_3)
$$= \left(\frac{1}{OP}\right)(OP)$$

$$= 1.$$

In general,

$$\mathbf{a}_m \cdot \mathbf{b}_n = 1, \quad \text{if } m = n,$$

$$= 0, \quad \text{if } m \neq n. \tag{4}$$

The fact that H_{hkl} is normal to (hkl) and H_{hkl} is the reciprocal of d_{hkl} may be proved as follows. Let ABC of Fig. A1-6 be part of the plane nearest the origin in the set (hkl). Then, from the definition of Miller indices, the vectors from the origin to the points A, B, and C are \mathbf{a}_1/h , \mathbf{a}_2/k , and \mathbf{a}_3/l , respectively. Consider the vector \mathbf{AB} , that is, a vector drawn from A to B, lying in the plane (hkl). Since

$$\frac{\mathbf{a}_1}{h} + \mathbf{AB} = \frac{\mathbf{a}_2}{k},$$

then

$$\mathbf{AB} = \frac{\mathbf{a}_2}{k} - \frac{\mathbf{a}_1}{h} \,.$$

Forming the dot product of H and AB, we have

$$\mathbf{H} \cdot \mathbf{AB} = (h\mathbf{b}_1 + k\mathbf{b}_2 + l\mathbf{b}_3) \cdot \left(\frac{\mathbf{a}_2}{k} - \frac{\mathbf{a}_1}{h}\right).$$

Evaluating this with the aid of Eqs. (4) and (5), we find

$$\mathbf{H} \cdot \mathbf{AB} = 1 - 1 = 0.$$

Since this product is zero, \mathbf{H} must be normal to \mathbf{AB} . Similarly, it may be shown that \mathbf{H} is normal to \mathbf{AC} . Since \mathbf{H} is normal to two vectors in the plane (hkl), it is normal to the plane itself.

To prove the reciprocal relation between H and d, let \mathbf{n} be a unit vector in the direction of \mathbf{H} , i.e., normal to (hkl). Then

$$d = ON = \frac{\mathbf{a}_1}{h} \cdot \mathbf{n}.$$

But

$$\mathbf{n} = \frac{\mathbf{H}}{H}.$$

Therefore

$$d = \frac{\mathbf{a}_1}{h} \cdot \frac{\mathbf{H}}{H}$$

$$= \frac{\mathbf{a}_1}{h} \cdot \frac{(h\mathbf{b}_1 + k\mathbf{b}_2 + l\mathbf{b}_3)}{H}$$

$$= \frac{1}{H}.$$

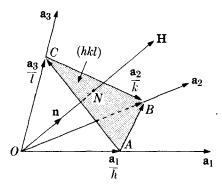


Fig. A1-6 Relation between reciprocal-lattice vector H and crystal plane (hkl).

Used purely as a geometrical tool, the reciprocal lattice is of considerable help in the solution of many problems in crystal geometry. Consider, for example, the relation between the planes of a zone and the axis of that zone. Since the planes of a zone are all parallel to one line, the zone axis, their normals must be coplanar. This means that planes of a zone are represented, in the reciprocal lattice, by a set of points lying on a plane passing through the origin of the reciprocal lattice. If the plane (hkl) belongs to the zone whose axis is [uvw], then the normal to (hkl), namely, H, must be perpendicular to [uvw]. Express the zone axis as a vector in the crystal lattice and H as a vector in the reciprocal lattice:

Zone axis =
$$u\mathbf{a}_1 + v\mathbf{a}_2 + w\mathbf{a}_3$$
,
 $\mathbf{H} = h\mathbf{b}_1 + k\mathbf{b}_2 + l\mathbf{b}_3$.

If these two vectors are perpendicular, their dot product must be zero:

$$(u\mathbf{a}_1 + v\mathbf{a}_2 + w\mathbf{a}_3) \cdot (h\mathbf{b}_1 + k\mathbf{b}_2 + l\mathbf{b}_3) = 0,$$

 $hu + kv + lw = 0.$

This is the relation given without proof in Sec. 2-6. By similar use of reciprocallattice vectors, other problems of crystal geometry, such as the derivation of the plane-spacing equations given in Appendix 3, may be greatly simplified.

A1-4 DIFFRACTION AND THE RECIPROCAL LATTICE

The great utility of the reciprocal lattice, however, lies in its connection with diffraction problems. We shall consider how x-rays scattered by the atom O at the origin of the crystal lattice (Fig. A1-7) are affected by those scattered by any other atom A whose coordinates with respect to the origin are $p\mathbf{a}_1$, $q\mathbf{a}_2$ and $r\mathbf{a}_3$, where p, q, and r are integers. Thus,

$$\mathbf{OA} = p\mathbf{a}_1 + q\mathbf{a}_2 + r\mathbf{a}_3.$$

Let the incident x-rays have a wavelength λ , and let the incident and diffracted beams be represented by the unit vectors S_0 and S, respectively. S_0 , S, and OA are, in general, not coplanar.

To determine the conditions under which diffraction will occur, we must determine the phase difference between the rays scattered by the atoms O and A. The lines Ou and Ov in Fig. A1-7 are wave fronts perpendicular to the incident beam S_0 and the scattered beam S, respectively. Let δ be the path difference for rays scattered by O and A. Then

$$\delta = uA + Av$$

$$= Om + On$$

$$= S_0 \cdot OA + (-S) \cdot OA$$

$$= -OA \cdot (S - S_0).$$

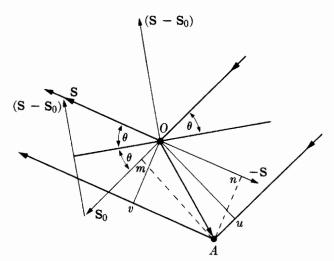


Fig. A1-7 X-ray scattering by atoms at O and A. After Guinier [G.10].

The corresponding phase difference, in radians, is given by

$$\phi = \frac{2\pi\delta}{\lambda}$$

$$= -2\pi \left(\frac{\mathbf{S} - \mathbf{S}_0}{\lambda}\right) \cdot \mathbf{OA}.$$
 (6)

Diffraction is now related to the reciprocal lattice by expressing the vector $(S - S_0)/\lambda$ as a vector in that lattice. Let

$$\frac{\mathbf{S}-\mathbf{S}_0}{\lambda}=h\mathbf{b}_1+k\mathbf{b}_2+l\mathbf{b}_3.$$

This is now in the form of a vector in reciprocal space but, at this point, no particular significance is attached to the parameters h, k, and l. They are continuously variable and may assume any values, integral or nonintegral. Equation (6) now becomes

$$\phi = -2\pi(h\mathbf{b}_1 + k\mathbf{b}_2 + l\mathbf{b}_3) \cdot (p\mathbf{a}_1 + q\mathbf{a}_2 + r\mathbf{a}_3) = -2\pi(hp + kq + lr).$$

A diffracted beam will be formed only if reinforcement occurs, and this requires that ϕ be an integral multiple of 2π . This can happen only if h, k, and l are integers. Therefore the condition for diffraction is that the vector $(S - S_0)/\lambda$ end on a *point* in the reciprocal lattice, or that

$$\left| \frac{\mathbf{S} - \mathbf{S}_0}{\lambda} = \mathbf{H} = h\mathbf{b}_1 + k\mathbf{b}_2 + l\mathbf{b}_3 \right|, \tag{7}$$

where h, k, and l are now restricted to integral values.

Both the Laue equations and the Bragg law can be derived from Eq. (7). The former are obtained by forming the dot product of each side of the equation and the three crystal-lattice vectors \mathbf{a}_1 , \mathbf{a}_2 , \mathbf{a}_3 successively. For example,

$$\mathbf{a}_1 \cdot \left(\frac{\mathbf{S} - \mathbf{S}_0}{\lambda}\right) = \mathbf{a}_1 \cdot (h\mathbf{b}_1 + k\mathbf{b}_2 + l\mathbf{b}_3)$$

$$= h$$

or

$$\mathbf{a}_1 \cdot (\mathbf{S} - \mathbf{S}_0) = h\lambda. \tag{8}$$

Similarly,

$$\mathbf{a}_2 \cdot (\mathbf{S} - \mathbf{S}_0) = k\lambda, \tag{9}$$

$$\mathbf{a}_3 \cdot (\mathbf{S} - \mathbf{S}_0) = l\lambda. \tag{10}$$

Equations (8) through (10) are the vector form of the equations derived by von Laue in 1912 to express the necessary conditions for diffraction. They must be satisfied simultaneously for diffraction to occur.

As shown in Fig. A1-7, the vector $(S - S_0)$ bisects the angle between the incident beam S_0 and the diffracted beam S. The diffracted beam S can therefore be considered as being reflected from a set of planes perpendicular to $(S - S_0)$. In fact, Eq. (7) states that $(S - S_0)$ is parallel to H, which is in turn perpendicular to the planes (hkl). Let θ be the angle between S (or S_0) and these planes. Then, since S and S_0 are unit vectors,

 $(S - S_0) = 2 \sin \theta.$

Therefore

$$\frac{2\sin\theta}{\lambda} = \frac{S - S_0}{\lambda} = H = \frac{1}{d},$$

or

$$\lambda = 2d \sin \theta$$
.

The conditions for diffraction expressed by Eq. (7) may be represented graphically by the "Ewald construction" shown in Fig. A1-8. The vector S_0/λ is drawn parallel to the incident beam and $1/\lambda$ in length. The terminal point O of this vector is taken as the origin of the reciprocal lattice, drawn to the same scale as the vector S_0/λ . A sphere of radius $1/\lambda$ is drawn about C, the initial point of the incident-beam vector. Then the condition for diffraction from the (hkl) planes is that the point hkl in the reciprocal lattice (point P in Fig. A1-8) touch the surface of the sphere, and the direction of the diffracted-beam vector S/λ is found by joining C to P. When this condition is fulfilled, the vector OP equals both H_{hkl} and $(S - S_0)/\lambda$, thus satisfying Eq. (7). Since diffraction depends on a reciprocallattice point touching the surface of the sphere drawn about C, this sphere is known as the "sphere of reflection."

Our initial assumption that p, q, and r are integers apparently excludes all crystals except those having only one atom per cell, located at the cell corners. For if the unit cell contains more than one atom, then the vector \mathbf{OA} from the origin to "any atom" in the crystal may have nonintegral coordinates. However, the

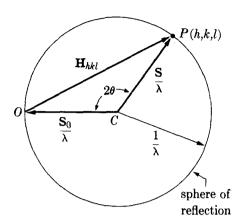


Fig. A1-8 The Ewald construction. Section through the sphere of reflection containing the incident and diffracted beam vectors.

presence of these additional atoms in the unit cell affects only the intensities of the diffracted beams, not their directions, and it is only the diffraction directions which are predicted by the Ewald construction. Stated in another way, the reciprocal lattice depends only on the shape and size of the unit cell of the crystal lattice and not at all on the arrangement of atoms within that cell. If we wish to take atom arrangement into consideration, we may weight each reciprocal-lattice point hkl with the appropriate value of the scattering power $(=|F|^2$, where F is the structure factor) of the particular (hkl) planes involved. Some planes may then have zero scattering power, thus eliminating some reciprocal-lattice points from consideration, e.g., all reciprocal-lattice points having odd values of (h + k + l) for body-centered crystals.

The common methods of x-ray diffraction are differentiated by the methods used for bringing reciprocal-lattice points into contact with the surface of the sphere of reflection. The radius of the sphere may be varied by varying the incident wavelength (Laue method), or the position of the reciprocal lattice may be varied by changes in the orientation of the crystal (rotating-crystal and powder methods).

A1-5 THE ROTATING-CRYSTAL METHOD

As stated in Sec. 3-6, when monochromatic radiation is incident on a single crystal rotated about one of its axes, the reflected beams lie on the surface of imaginary cones coaxial with the rotation axis. The way in which this reflection occurs may be shown very nicely by the Ewald construction. Suppose a simple cubic crystal is rotated about the axis [001]. This is equivalent to rotation of the reciprocal lattice about the \mathbf{b}_3 axis. Figure A1-9 shows a portion of the reciprocal lattice oriented in this manner, together with the adjacent sphere of reflection.

All crystal planes having indices (hk1) are represented by points lying on a plane (called the "l = 1 layer") in the reciprocal lattice, normal to b_3 . When the reciprocal lattice rotates, this plane cuts the reflection sphere in the small circle shown, and any points on the l = 1 layer which touch the sphere surface must

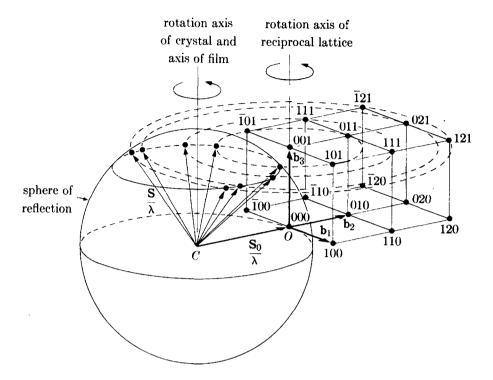


Fig. A1-9 Reciprocal-lattice treatment of rotating-crystal method.

touch it on this circle. Therefore all diffracted-beam vectors S/λ must end on this circle, which is equivalent to saying that the diffracted beams must lie on the surface of a cone. In this particular case, all the hk1 points shown intersect the surface of the sphere sometime during their rotation about the b_3 axis, producing the diffracted beams shown in Fig. A1-9. In addition many hk0 and $hk\overline{1}$ reflections would be produced, but these have been omitted from the drawing for the sake of clarity.

This simple example may suggest how the rotation photograph of a crystal of unknown structure, and therefore having an unknown reciprocal lattice, can yield clues as to the distribution in space of reciprocal-lattice points. By taking a number of photographs with the crystal rotated successively about various axes, the crystallographer gradually discovers the complete distribution of reflecting points. Once the reciprocal lattice is known, the crystal lattice is easily derived, because it is a corollary of Eqs. (1) through (3) that the reciprocal of the reciprocal lattice is the crystal lattice.

A1-6 THE POWDER METHOD

The random orientations of the individual crystals in a powder specimen are equivalent to the rotation of a single crystal about all possible axes during the x-ray exposure. The reciprocal lattice therefore takes on all possible orientations relative to the incident beam, but its origin remains fixed at the end of the S_0/λ vector.

Consider any point hkl in the reciprocal lattice, initially at P_1 (Fig. A1-10). This point can be brought into a reflecting position on the surface of the reflection

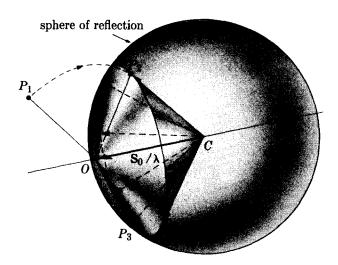


Fig. A1-10 Formation of a cone of diffracted rays in the powder method.

sphere by a rotation of the lattice about an axis through O and normal to OC, for example. Such a rotation would move P_1 to P_2 . But the point hkl can still remain on the surface of the sphere [i.e., reflection will still occur from the same set of planes (hkl)] if the reciprocal lattice is then rotated about the axis OC, since the point hkl will then move around the small circle P_2P_3 . During this motion, the H vector sweeps out a cone whose apex is at O, and the diffracted beams all lie on the surface of another cone whose apex is at C. The axes of both cones coincide with the incident beam.

The number of different hkl reflections obtained on a powder photograph depends, in part, on the relative magnitudes of the wavelength and the crystal-lattice parameters or, in reciprocal-lattice language, on the relative sizes of the sphere of reflection and the reciprocal-lattice unit cell. To find the number of reflections we may regard the reciprocal lattice as fixed and the incident-beam vector S_0/λ as rotating about its terminal point through all possible positions. The reflection sphere therefore swings about the origin of the reciprocal lattice and sweeps out a sphere of radius $2/\lambda$, called the "limiting sphere" (Fig. A1-11). All reciprocal-lattice points within the limiting sphere can touch the surface of the reflection sphere and cause reflection to occur.

It is also a corollary of Eqs. (1) through (3) that the volume v of the reciprocallattice unit cell is the reciprocal of the volume V of the crystal unit cell. Since there is one reciprocal-lattice point per cell of the reciprocal lattice, the number of reciprocal-lattice points within the limiting sphere is given by

$$n = \frac{(4\pi/3)(2/\lambda)^3}{v} = \frac{32\pi V}{3\lambda^3}.$$
 (11)

Not all of these n points will cause a separate reflection: some of them may have a zero structure factor, and some may be at equal distances from the reciprocal-lattice origin, i.e., correspond to planes of the same spacing. (The latter effect is taken care of by the multiplicity factor, since this gives the number of different planes in

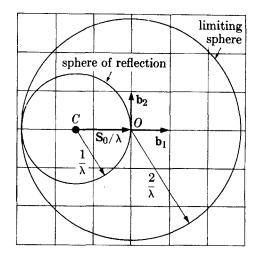


Fig. A1-11 The limiting sphere for the powder method.

a form having the same spacing.) However, Eq. (11) may always be used directly to obtain an upper limit to the number of possible reflections. For example, if $V = 50 \,\text{Å}^3$ and $\lambda = 1.54 \,\text{Å}$, then n = 460. If the specimen belongs to the triclinic system, this number will be reduced by a factor of only 2, the multiplicity factor, and the powder photograph will contain 230 separate diffraction lines! As the symmetry of the crystal increases, so does the multiplicity factor and the fraction of reciprocal-lattice points which have zero structure factor, resulting in a decrease in the number of diffraction lines. For example, the powder pattern of a diamond cubic element has only 5 lines, for the same values of V and λ assumed above.

A1-7 THE LAUE METHOD

Diffraction occurs in the Laue method because of the continuous range of wavelengths present in the incident beam. Stated alternatively, contact between a fixed reciprocal-lattice point and the sphere of reflection is produced by continuously varying the radius of the sphere. There is therefore a whole set of reflection spheres, not just one; each has a different center, but all pass through the origin of the reciprocal lattice. The range of wavelengths present in the incident beam is of course not infinite. It has a sharp lower limit at λ_{SWL} , the short-wavelength limit of the continuous spectrum; the upper limit is less definite but is often taken as the wavelength of the K absorption edge of the silver in the emulsion (0.48 Å), because the effective photographic intensity of the continuous spectrum drops abruptly at that wavelength [see Fig. 1-19(c)].

To these two extreme wavelengths correspond two extreme reflection spheres, as shown in Fig. A1-12, which is a section through these spheres and the l=0 layer of a reciprocal lattice. The incident beam is along the \mathbf{b}_1 vector, i.e., perpendicular to the (h00) planes of the crystal. The larger sphere shown is centered at B and has a radius equal to the reciprocal of $\lambda_{\rm SWL}$, while the smaller sphere is centered at A and has a radius equal to the reciprocal of the wavelength of the silver K absorption edge.

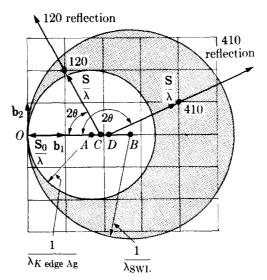


Fig. A1-12 Reciprocal-lattice treatment of the Laue method. $(S - S_0)/\lambda = H$.

There is a whole series of spheres lying between these two and centered on the line segment AB. Therefore any reciprocal-lattice point lying in the shaded region of the diagram is on the surface of one of these spheres and corresponds to a set of crystal planes oriented to reflect one of the incident wavelengths. In the forward direction, for example, a 120 reflection will be produced. To find its direction, we locate a point C on AB which is equidistant from the origin O and the reciprocallattice point 120; C is therefore the center of the reflection sphere passing through the point 120. Joining C to 120 gives the diffracted-beam vector S/λ for this reflection. The direction of the 410 reflection, one of the many backward-reflected beams, is found in similar fashion; here the reciprocal-lattice point in question is situated on a reflection sphere centered at D.

There is another way of treating the-Laue method which is more convenient for many purposes. The basic diffraction equation, Eq. (7), is rewritten in the form

$$\mathbf{S} - \mathbf{S}_0 = \lambda \mathbf{H} \quad . \tag{12}$$

Both sides of this equation are now dimensionless and the radius of the sphere of reflection is simply unity, since S and S_0 are unit vectors. But the position of the reciprocal-lattice points is now dependent on the wavelength used, since their distance from the origin of the reciprocal lattice is now given by λH .

In the Laue method, each reciprocal-lattice point (except 000) is drawn out into a line segment directed to the origin, because of the range of wavelengths present in the incident beam. The result is shown in Fig. A1-13,* which is drawn to correspond to Fig. A1-12. The point nearest the origin on each line segment has

^{*} In this figure, as well as in Figs. A1-11 and A1-12, the size of the reciprocal lattice, relative to the size of the reflection sphere, has been exaggerated for clarity.

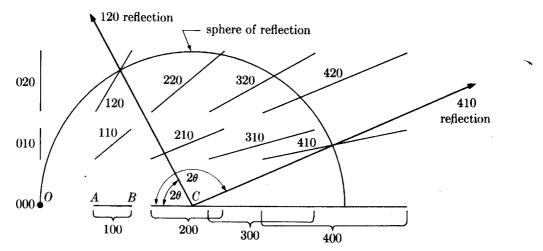


Fig. A1-13 Alternative reciprocal-lattice treatment of the Laue method. $S - S_0 = \lambda H$.

a value of λH corresponding to the shortest wavelength present, while the point on the other end has a value of λH corresponding to the longest effective wavelength. Thus the 100 reciprocal-lattice line extends from A to B, where $OA = \lambda_{\min} H_{100}$ and $OB = \lambda_{\max} H_{100}$. Since the length of any line increases as H increases, for a given range of wavelengths, overlapping occurs for the higher orders, as shown by 200, 300, 400, etc. The reflection sphere is drawn with unit radius, and reflection occurs whenever a reciprocal-lattice line intersects the sphere surface. Graphically, the advantage of this construction over that of Fig. A1-12 is that all diffracted beams are now drawn from the same point C, thus facilitating the comparison of the diffraction angles 2θ for different reflections.

This construction also shows why the diffracted beams from planes of a zone are arranged on a cone in the Laue method. All reciprocal-lattice lines representing the planes of one zone lie on a plane passing through the origin of the reciprocal lattice. This plane cuts the reflection sphere in a circle, and all the diffracted beam vectors S must end on this circle, thus producing a conical array of diffracted beams, the axis of the cone coinciding with the zone axis.

Another application of this construction, to the problem of temperature-diffuse scattering, will illustrate the general utility of the reciprocal-lattice method in treating diffuse scattering phenomena. The reciprocal lattice of any crystal may be regarded as a distribution of "scattered intensity" in reciprocal space, in the sense that a scattered beam will be produced whenever the sphere of reflection intersects a point in reciprocal space where the "scattered intensity" is not zero. If the crystal is perfect, the scattered intensity is concentrated at points in reciprocal space, the points of the reciprocal lattice, and is zero everywhere else. But if anything occurs to disturb the regularity of the crystal lattice, then these points become smeared out, and appreciable scattered intensity exists in regions of reciprocal space where h, k, and l are nonintegral. For example, if the atoms of the crystal are undergoing thermal vibration, then each point of the reciprocal lattice spreads out into a region which may be considered, to a first approximation, as roughly spherical in shape, as suggested by Fig. A1-14(a). In other words, the

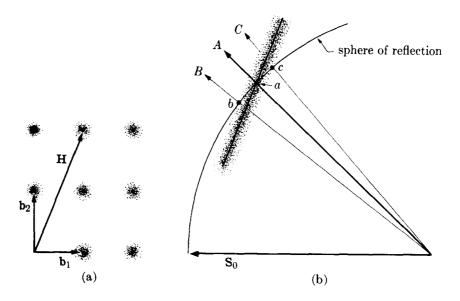


Fig. A1-14 The effect of thermal vibration on the reciprocal lattice.

thermally produced elastic waves which run through the crystal lattice so disturb the regularity of the atomic planes that the corresponding \mathbf{H} vectors end, not on points, but in small spherical regions. The scattered intensity is not distributed uniformly within each region: it remains very high at the central point, where h, k, and l are integral, and is very weak and diffuse in the surrounding volume, as indicated in the drawing.

What then will be the effect of thermal agitation on, for example, a transmission Laue pattern? If we use the construction of Fig. A1-13, i.e., if we make distances in the reciprocal lattice equal to λH , then each spherical volume in the reciprocal lattice will be drawn out into a rod, roughly cylindrical in shape and directed to the origin, as indicated in Fig. A1-14(b), which is a section through the reflection sphere and one such rod. The axis of each rod is a line of high intensity and this is surrounded by a low-intensity region. This line intersects the reflection sphere at a and produces the strong diffracted beam A, the ordinary Laue reflection. But on either side of A there are weak scattered rays, extending from B to C, due to the intersection, extending from b to c, of the diffuse part of the rod with the sphere of reflection. In a direction normal to the drawing, however, the diffuse rod intersects the sphere in an arc equal only to the rod diameter, which is much shorter than the arc bc. We are thus led to expect, on a film placed in the transmission position, a weak and diffuse streak running radially through the usual sharp, intense Laue spot.

Figure A1-15 shows an example of this phenomenon, often called thermal asterism because of the radial direction of the diffuse streaks. This photograph was obtained from aluminum at 280°C in 5 minutes. Actually, thermal agitation is quite pronounced in aluminum even at room temperature, and thermal asterism is usually evident in overexposed room-temperature photographs. Even in Fig. 3-6(a), which was given a normal exposure of about 15 minutes, radial streaks are

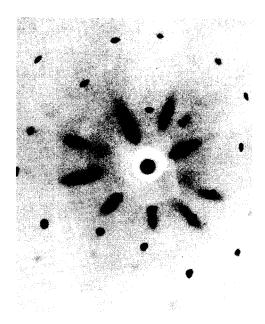


Fig. A1-15 Transmission Laue pattern showing thermal asterism. Aluminum crystal, 280°C, 5 min exposure.

faintly visible. In this latter photograph, there is a streak near the center that does not pass through any Laue spot: it is due to a reciprocal-lattice rod so nearly tangent to the reflection sphere that the sphere intersects only the diffuse part of the rod and not its axis.

The enlargement of reciprocal-lattice points caused by thermal vibration, depicted in Fig. A1-14(a), is not observed in powder patterns. It is so weak and diffuse that it is lost in the background.

APPENDIX 3

LATTICE GEOMETRY

A3-1 PLANE SPACINGS

The value of d, the distance between adjacent planes in the set (hkl), may be found from the following equations.

Cubic:
$$\frac{1}{d^2} = \frac{h^2 + k^2 + l^2}{a^2}$$

Tetragonal:
$$\frac{1}{d^2} = \frac{h^2 + k^2}{a^2} + \frac{l^2}{c^2}$$

Hexagonal:
$$\frac{1}{d^2} = \frac{4}{3} \left(\frac{h^2 + hk + k^2}{a^2} \right) + \frac{l^2}{c^2}$$

Rhombohedral:

$$\frac{1}{d^2} = \frac{(h^2 + k^2 + l^2)\sin^2\alpha + 2(hk + kl + hl)(\cos^2\alpha - \cos\alpha)}{a^2(1 - 3\cos^2\alpha + 2\cos^3\alpha)}$$

Orthorhombic:
$$\frac{1}{d^2} = \frac{h^2}{a^2} + \frac{k^2}{h^2} + \frac{l^2}{c^2}$$

Monoclinic:
$$\frac{1}{d^2} = \frac{1}{\sin^2 \beta} \left(\frac{h^2}{a^2} + \frac{k^2 \sin^2 \beta}{b^2} + \frac{l^2}{c^2} - \frac{2hl \cos \beta}{ac} \right)$$

Triclinic:
$$\frac{1}{d^2} = \frac{1}{V^2} (S_{11}h^2 + S_{22}k^2 + S_{33}l^2 + 2S_{12}hk + 2S_{23}kl + 2S_{13}hl)$$

In the equation for triclinic crystals,

$$V = \text{volume of unit cell (see below)},$$

$$S_{11} = b^2 c^2 \sin^2 \alpha,$$

$$S_{22} = a^2c^2\sin^2\beta.$$

$$S_{33} = a^2b^2 \sin^2 \gamma,$$

$$S_{12} = abc^2(\cos\alpha\cos\beta - \cos\gamma),$$

$$S_{23} = a^2bc(\cos\beta\cos\gamma - \cos\alpha),$$

$$S_{13} = ab^2c(\cos\gamma\cos\alpha - \cos\beta).$$

A3-2 CELL VOLUMES

The following equations give the volume V of the unit cell.

Cubic:
$$V = a^3$$

Tetragonal:
$$V = a^2c$$

Hexagonal:
$$V = \frac{\sqrt{3} a^2 c}{2} = 0.866a^2 c$$

Rhombohedral:
$$V = a^3 \sqrt{1 - 3\cos^2 \alpha + 2\cos^3 \alpha}$$

Orthorhombic:
$$V = abc$$

Monoclinic:
$$V = abc \sin \beta$$

Triclinic:
$$V = abc\sqrt{1 - \cos^2 \alpha - \cos^2 \beta - \cos^2 \gamma + 2\cos \alpha \cos \beta \cos \gamma}$$

A3-3 INTERPLANAR ANGLES

The angle ϕ between the plane $(h_1k_1l_1)$, of spacing d_1 , and the plane $(h_2k_2l_2)$, of spacing d_2 , may be found from the following equations. (V is the volume of the unit cell.)

Cubic:
$$\cos \phi = \frac{h_1 h_2 + k_1 k_2 + l_1 l_2}{\sqrt{(h_1^2 + k_1^2 + l_1^2)(h_2^2 + k_2^2 + l_2^2)}}$$

Tetragonal:
$$\cos \phi = \frac{\frac{h_1 h_2 + k_1 k_2}{a^2} + \frac{l_1 l_2}{c^2}}{\sqrt{\left(\frac{h_1^2 + k_1^2}{a^2} + \frac{l_1^2}{c^2}\right)\left(\frac{h_2^2 + k_2^2}{a^2} + \frac{l_2^2}{c^2}\right)}}$$

Hexagonal:

$$\cos \phi = \frac{h_1 h_2 + k_1 k_2 + \frac{1}{2} (h_1 k_2 + h_2 k_1) + \frac{3a^2}{4c^2} l_1 l_2}{\sqrt{\left(h_1^2 + k_1^2 + h_1 k_1 + \frac{3a^2}{4c^2} l_1^2\right) \left(h_2^2 + k_2^2 + h_2 k_2 + \frac{3a^2}{4c^2} l_2^2\right)}}$$

Rhombohedral:

$$\cos \phi = \frac{a^4 d_1 d_2}{V^2} \left[\sin^2 \alpha (h_1 h_2 + k_1 k_2 + l_1 l_2) + (\cos^2 \alpha - \cos \alpha) (k_1 l_2 + k_2 l_1 + l_1 h_2 + l_2 h_1 + h_1 k_2 + h_2 k_1) \right]$$

Orthorhombic:
$$\cos \phi = \frac{\frac{h_1 h_2}{a^2} + \frac{k_1 k_2}{b^2} + \frac{l_1 l_2}{c^2}}{\sqrt{\left(\frac{h_1^2}{a^2} + \frac{k_1^2}{b^2} + \frac{l_1^2}{c^2}\right)\left(\frac{h_2^2}{a^2} + \frac{k_2^2}{b^2} + \frac{l_2^2}{c^2}\right)}}$$

Monoclinic:

$$\cos \phi = \frac{d_1 d_2}{\sin^2 \beta} \left[\frac{h_1 h_2}{a^2} + \frac{k_1 k_2 \sin^2 \beta}{b^2} + \frac{l_1 l_2}{c^2} - \frac{(l_1 h_2 + l_2 h_1) \cos \beta}{ac} \right]$$

Triclinic:

$$\cos \phi = \frac{d_1 d_2}{V^2} \left[S_{11} h_1 h_2 + S_{22} k_1 k_2 + S_{33} l_1 l_2 + S_{23} (k_1 l_2 + k_2 l_1) + S_{13} (l_1 h_2 + l_2 h_1) + S_{12} (h_1 k_2 + h_2 k_1) \right]$$

Appendix 7

Some commonly used K wavelengths

Element	Kα (weighted average)*	Kα ₂ strong	Κα ₁ very strong	Kβ ₁ weak
Cr	2.29100	2.293606	2.28970	2.08487
Fe	1.937355	1.939980	1.936042	1.75661
Co	1.790260	1.792850	1.788965	1.62079
Cu	1.541838	1.544390	1.540562	1.392218
Мо	0.710730	0.713590	0.709300	0.632288

^{*} $K\alpha_1$ is given twice the weight of $K\alpha_2$.

Characteristic L Lines of Tungsten

Line	Relative intensity	Wavelength
<i>L</i> α ₁	Very strong	1.47639
$L\alpha_2$	Weak	1.48743
$L\beta_1$	Strong	1.281809
$L\beta_2$	Medium	1.24460
$L\beta_3$	Weak	1.26269
L_{γ_1}	Weak	1.09855

APPENDIX 10 QUADRATIC FORMS OF MILLER INDICES

		Cubic			Hexagono	ıl
		h	kl			
$h^2 + k^2 + l^2$	Simple	Face- centered	Body- centered	Diamond	$h^2 + hk + k^2$	hk
1 2	100 110		110		1 2	10
3	111	iii		111	3	11
4	200	200	200		4	20
4 5 6	210 211		211		5 6	
7	211		211		7	21
8	220	220	220	220	8	
9	300, 221				9	30
10	310		310		10	
11	311	311		311	11	
12	222	222	222		12	22
13	320				13	31
14	321		321		14 15	
15 16	400	400	400	400	16	40
17	410, 322	400	400	700	17	40
18	411, 330		411, 330		18	
19	331	331		331	19	32
20	420	420	420		20	
21	421				21	41
22	332		332		22	
23					23	
24	422	422	422	422	24	
2 5	500, 430		510, 431		25 26	50
26 27	510, 431 511, 333	511, 333	310, 431	511, 333	27	33
28	311, 333	311,000		3,555	28	42
29	520, 432				29	
30	521		521		30 31	51
31 32	440	440	440	440	32	J.
33	522, 441				33	
34	530, 433		530, 433		34	ĺ
35	531	531	(00 110	531	35	40
36	600, 442	600, 442	600, 442		36 37	60 43
37 38	610 611, 532		611, 532		38	75
39	011,302		011,002		39	5 2
40	620	620	620	620	40	
40 41	621, 540, 443	020	020	320	41	
42	541		541		42	
43	533	533		533	43	61
44	622	622	622		44	
45	630, 542				45	
46	631		631		46	
47	444	444	444	444	47 48	44
48 49	700, 632	444			49	70, 53

	Hexagonal					
$h^2 + k^2 + l^2$	Simple	Face- centered	Diamond	$h^2 + hk + k^2$	hk	
50 51 52 53 54	710, 550, 543 711, 551 640 720, 641 721, 633, 552	711, 551 640	710, 550, 543 640 721, 633, 552	711, 551	50 51 52 53 54	62
55 56 57 58 59	642 722, 544 730 731, 553	642 731, 553	642 730	642 731, 553	55 56 57 58 59	71

APPENDIX 12 ATOMIC SCATTERING FACTORS

$\frac{\sin\theta}{\lambda} (\mathring{A}^{-1})$	0.0	0.1	0.2	0.3	0.4	0.5	0.6	0.7	0.8	0.9	1.0	1.1	1.2
Н	1	0.81	0.48	0.25	0.13	0.07	0.04	0.03	0.02	0.01	0.00	0.00	
He	2	1.88	1.46	1.05	0.75	0.52	0.35	0.24	0.18	0.14	0.11	0.09	
Li+	2	1.96	1.8	1.5	1.3	1.0	0.8	0.6	0.5	0.4	0.3	0.3	
Li	3	2.2	1.8	1.5	1.3	1.0	0.8	0.6	0.5	0.4	0.3	0.3	
Be +2	2	2.0	1.9	1.7	1.6	1.4	1.2	1.0	0.9	0.7	0.6	0.5	
Ве В +3	4	2.9 1.99	1.9	1.7	1.6	1.4	1.2	1.0	0.9	0.7	0.6	0.5	
В	2 5	3.5	1.9 2.4	1.8	1.7	1.6 1.5	1.4	1.3	1.2 1.2	1.0	0.9	0.7 0.7	
Č	6	4.6	3.0	2.2	1.9	1.7	1.6	1.4	1.3	1.16	1.0	0.9	
N+5	2	2.0	2.0	1.9	1.9	1.8	1.7	1.6	1.5	1.4	1.3	1.16	
N +3	4	3.7	3.0	2.4	2.0	1.8	1.66	1.56	1.49	1.39	1.28	1.17	
N	7	5.8	4.2	3.0	2.3	1.9	1.65	1.54	1.49	1.39	1.29	1.17	
0	8	7.1	5.3	3.9	2.9	2.2	1.8	1.6	1.5	1.4	1.35	1.26	
O -2	10	8.0	5.5	3.8	2.7	2.1	1.8	1.5	1.5	1.4	1.35	1.26	
F	9	7.8	6.2	4.45	3.35	2.65	2.15	1.9	1.7	1.6	1.5	1.35	
F-	10	8.7	6.7	4.8	3.5	2.8	2.2	1.9	1.7	1.55	1.5	1.35	
Ne	10	9.3	7.5	5.8	4.4	3.4	2.65	2.2	1.9	1.65	1.55	1.5	
Na +	10	9.5	8.2	6.7	5.25	4.05	3.2	2.65	2.25	1.95	1.75	1.6	
Na	11	9.65	8.2	6.7	5.25	4.05	3.2	2.65	2.25	1.95	1.75	1.6	
Mg $^{+2}$	10	9.75	8.6	7.25	5.95	4.8	3.85	3.15	2.55	2.2	2.0	1.8	
Mg Al ⁺³	·12		-8.6	7.25	5.95	4.8	3.85	3.15	2.55	2.2	2.0	1.8	
Al Al	10	9.7	8.9	7.8	6.65	5.5	4.45	3.65	3.1 3.1	2.65	2.3	2.0	
Si +4	13 10	11.0 9.75	8.95 9.15	7.75 8.25	6.6 7.15	5.5 6.05	4.5 5.05	3.7 4.2	3.4	2.65 2.95	2.3 2.6	2.0 2.3	
Si	14	11.35	9.4	8.2	7.15	6.1	5.1	4.2	3.4	2.95	2.6	2.3	
p +5	10	9.8	9.25	8.45	7.5	6.55	5. 6 5	4.8	4.05	3.4	3.0	2.6	
P	15		10.0	8.45	7.45	6.5	5.65	4.8	4.05	3.4	3.0	2.6	
p −3	18	12.7	9.8	8.4	7.45	6.5	5.65	4.85	4.05	3.4	3.0	2.6	
S +6	10	9.85	9.4	8.7	7.85	6.85	6.05	5.25	4.5	3.9	3.35	2.9	
S	16	13.6	10.7	8.95	7.85	6.85	6.0	5.25	4.5	3.9	3.35	2.9	
S ⁻²	18	14.3	10.7	8.9	7.85	6.85	6.0	5.25	4.5	3.9	3.35	2.9	
CI	17		11.3	9.25	8.05	7.25	6.5	5.75	5.05	4.4	3.85	3.35	
CI-	18	15.2	11.5	9.3	8.05	7.25	6.5	5.75	5.05	4.4	3.85	3.35	
A	18			10.4	8.7	7.8	7.0	6.2	5.4	4.7	4.1	3.6	
K +	18	16.5	13.3	10.8	8.85	7.75	7.05	6.44	5.9	5.3	4.8	4.2	
K	19			10.8	9.2	7.9	6.7	5.9	5.2	4.6	4.2	3.7	3.3
Ca +2	18	16.8		11.5	9.3	8.1	7.35	6.7	6.2	5.7	5.1	4.6	
Ca	20			11.4	9.7	8.4	7.3	6.3	5.6	4.9	4.5	4.0	3.6
Sc ⁺³	18	16.7		11.4	9.4	8.3	7.6	6.9	6.4	5.8	5.35	4.85	
Sc	21	18.4	14.9	12.1	10.3	8.9	7.7	6.7	5.9	5.3	4.7	4.3	3.9
Ti +4	18			11.9	9.9	8.5	7.85	7.3	6.7	6.15	5.65	5.05	
Ti	22			12.8	10.9	9.5	8.2	7.2	6.3	5.6	5.0	4.6	4.2
V	23	20.2		13.5	11.5	10.1	8.7	7.6	6.7	5.9	5.3	4.9	4.4
Cr	24	21.1		14.2	12.1	10.6	9.2	8.0	7.1	6.3	5.7	5.1	4.6
Mn	25	22.1	18.2	14.9	12.7	11.1	9.7	8.4	7.5	6.6	6.0	5.4	4.9

$\frac{\sin\theta}{\lambda}(\mathring{\mathbf{A}}^{-1})$	0.0	0.1	0.2	0.3	0.4	0.5	0.6	0.7	0.8	0.9	1.0	1.1	1.2
Fe	26	23.1	18.9	15.6	1	11.6	10.2	8.9	7.9	7.0	6.3	5.7	5.2
Co	27	24.1	19.8	16.4	14.0	12.1	10.7	9.3	8.3	7.3	6.7	6.0	5.5
Ni	28	25.0	20.7	17.2	14.6	12.7	11.2	9.8	8.7	7.7	7.0	6.3	5.8
Cυ	29	25.9	21.6	17.9	15.2	13.3	11.7	10.2	9.1	8.1	7.3	6.6	6.0
Zn	30	26.8	22.4	18.6	15.8	13.9	12.2	10.7	9.6	8.5	7.6	6.9	6.3
Ga	31	27.8	23.3	19.3	16.5	14.5	12.7	11.2	10.0	8.9	7.9	7.3	6.7
Ge	32	28.8	24.1	20.0	17.1	15.0	13.2	11.6	10.4	9.3	8.3	7.6	7.0
As	33	29.7	25.0	20.8	17.7	15.6	13.8	12.1	10.8	9.7	8.7	7.9	7.3
Se	34	30.6	25.8	21.5	18.3	16.1	14.3	12.6	11.2	10.0	9.0	8.2	7.5
Br	35	31.6	26.6	22.3	18.9	16.7	14.8	13.1	11.7	10.4	9.4	8.6	7.8
Kr	36	32.5	27.4	23.0	19.5	17.3	15.3	13.6	12.1	10.8	9.8	8.9	8.1
Rb+	36	33.6	28.7	24.6	21.4	18.9	16.7	14.6	12.8	11.2	9.9	8.9	\
Rb	37	33.5	28.2	23.8	20.2	17.9	15.9	14.1	12.5	11.2	10.2	9.2	8.4
Sr	38	34.4	29.0	24.5	20.8	18.4	16.4	14.6	12.9	11.6	10.5	9.5	8.7
Y	39	35.4	29 .9	25.3	21.5	19.0	17.0	15.1	13.4	12.0	10.9	9.9	9.0
Zr	40	36.3	30.8	26.0	22.1	19.7	17.5	15.6	13.8	12.4	11.2	10.2	9.3
Nb	41	37.3	31.7	26.8	22.8	20.2	18.1	16.0	14.3	12.8	11.6	10.6	9.7
Mo	42	38.2	32.6	27.6	23.5	20.8	18.6	16.5	14.8	13.2	12.0	10.9	10.0
Tc	43	39.1	33.4	28.3	24.1	21.3	19.1	17.0	15.2	13.6	12.3	11.3	10.3
Ru	44	40.0	34.3	29 .1	24.7	21.9	19.6	17.5	15.6	14.1	12.7	11.6	10.6
Rh	45	41.0	35.1	29.9	25.4	22.5	20.2	18.0	16.1	14.5	13.1	12.0	11.0
Pd	46	41.9	36.0	30.7	26.2	23.1	20.8	18.5	16.6	14.9	13.6	12.3	11.3
Ag	47	42.8	36.9	31.5	26.9	23.8	21.3	19.0	17.1	15.3	14.0	12.7	11.7
Cq	48	43.7	37.7	32.2	27.5	24.4	21.8	19.6	17.6	15.7	14.3	13.0	12.0
In	49	44.7	38.6	33.0	28.1	2 5.0	22.4	20.1	18.0	16.2	14.7	13.4	12.3
Sn	50	45.7	39.5	33.8	28.7	25.6	22.9	20.6	18.5	16.6	15.1	13.7	12.7
Sb	51	46.7	40.4	34.6	29.5	26.3	23.5	21.1	19.0	17.0	15.5	14.1	13.0
Te	52	47.7	41.3	35.4	30.3	26.9	24.0	21.7	19.5	17.5	16.0	14.5	13.3
I	53	48.6	42.1	36.1	31.0	27 .5	24.6	22.2	20.0	17.9	16.4	14.8	13.6
Xe	54	49.6	43.0	36.8	31.6	28.0	25.2	22.7	20.4	18.4	16.7	15.2	13.9
Cs	- 55	50.7	43.8	37.6	32.4	28.7	25.8	23.2	20.8	18.8	17.0	15.6	14.5
Ba	56	51.7	44.7	38.4	33.1	29.3	26.4	23.7	21.3	19.2	17.4	16.0	14.7
La	57	52.6	45.6	39.3	33.8	29.8	26.9	24.3	21.9	19.7	17.9	16.4	15.0
Ce	58	53.6	46.5	40.1	34.5	30.4	27.4	24.8	22.4	20.2	18.4	16.6	15.3
Pr	59	54. 5	47.4	40.9	35.2	31.1	28.0	25.4	22.9	20.6	18.8	17.1	15.7
Nd	60	55.4		41.6	35.9	31.8	28.6	25.9	23.4	21.1	19.2	17.5	16.1
Pm	61			42.4		32.4		26.4		21.5	19.6	17.9	16.4
Sm	62			43.2	37.3	32.9	29 .8	26.9		22.0	20.0	18.3	16.8
Ευ	63	58.3	50.9	44.0	38.1	33.5	30.4	27.5	24.9	22.4	20.4	18.7	17.1
Gd '	64	59.3	51.7	44.8	38.8	34.1	31.0	28 .J	25.4	22.9	20.8	19.1	17.5
Ть	65	60.2	52.6	-	39.6			28.6	25.9	23.4	21.2	19.5	17.9
Dy	66	61.1		46.5		35.4	32.2	29.2	26.3		21.6	19.9	18.3
Ho	67		54.5		41.1	36.1	32.7	29.7			22.0	20.3	18.6
Er	68			48.1	41.7	36.7		30.2	27.3	24 . 7	22.4	20.7	18.9
Tm	69	64.0	56.2	48.9	42.4	37.4	33.9	30.8	27.9		22.9	21.0	19.3

$\frac{\sin\theta}{\lambda}$ (Å ⁻¹)	0.0	0.1	0.2	0.3	0.4	0.5	0.6	0.7	0.8	0.9	1.0.	1.1	1.2
Υb	70	64.9	57.0	49.7	43.2	38.0	34.4	31.3	28.4	25.7	23.3	21.4	19.7
Lu	71	65.9	57.8	50.4	43.9	38.7	35.0	31.8	28.9	26.2	23.8	21.8	20.0
Hf	72	66.8	58. 6	51.2	44.5	39.3	35.6	32.3	29.3	26.7	24.2	22.3	20.4
Ta	73	67.8	59.5	52.0	45.3	39.9	36.2	32.9	29.8	27.1	24.7	22.6	20.9
W	74	68 .8	60.4	52.8	46.1	40.5	36.8	33.5	30.4	27.6	25.2	23.0	21.3
Re	75	<i>6</i> 9.8	61.3	53.6	46.8	41.1	37.4	34.0	30.9	28.1	25.6	23.4	21.6
Os	76	70.8	62.2	54.4	47.5	41.7	38.0	34.6	31.4	28.6	26.0	23.9	22.0
Ir	77	71. 7	63.1	55.3	48.2	42.4	38.6	35.1	32.0	29.0	26.5	24.3	22.3
Pt	<i>7</i> 8	72.6	64.0	56.2	48.9	43.1	39.2	35.6	32.5	29.5	27.0	24.7	22.7
Aυ	79	73.6	65.0	57.0	49.7	43.8	39.8	36.2	33.1	30.0	27.4	25.1	23.1
Hg	80	74.6	65.9	57.9	50.5	44.4	40.5	36.8	33.6	30.6	27.8	25.6	23.6
ΤĬ	81	75.5	66.7	58.7	51.2	45.0	41.1	37.4	34.1	31.1	28.3	26.0	24.1
Pb	82	76.5	67 .5	59.5	51.9	45.7	41.6	37.9	34.6	31.5	28.8	26.4	24.5
Bi	83	77.5	68.4	60.4	52.7	46.4	42.2	38.5	35.1	32.0	29.2	26.8	24.8
Po	84	78. 4	69.4	61.3	53.5	47.1	42.8	39.1	35.6	32.6	29.7	27.2	25.2
At	85	79.4	70.3	62.1	54.2	47.7	43.4	39.6	36.2	33 .1	30.1	27.6	25.6
Rn	86	80.3	71.3	63.0	55.1	48.4	44.0	40.2	36.8	33.5	30.5	28.0	26.0
Fr	87	81.3	72.2	63.8	55.8	49.1	44.5	40.7	37.3	34.0	31.0	28.4	26.4
Rα	88	82.2	73.2	64.6	56.5	49.8	45.1	41.3	37.8	34.6	31.5	28.8	26.7
Ac	89	83.2	74 . 1	65 .5	57.3	50.4	45.8	41.8	38.3	35.1	32.0	29 .2	27 .1
Th	90	84.1	<i>7</i> 5.1	66.3	58.1	51.1	46.5	42.4	38.8	35.5	32.4	29.6	27.5
Pa	91	85.1	76.0	67.1	58.8	51.7	47.1	43.0	39.3	36.0	32.8	30.1	27.9
υ	92	86.0	76.9	67.9	59.6	52.4	47.7	43.5	39.8	36.5	33.3	30.6	28.3
Np	93	87	<i>7</i> 8	69	60	53	48	44	40	37	34	31	29
Pu	94	88	79	69	61	54	49	44	41	38	34	31	29
Am	95	89	79	70	62	55	50	45	42	38	35	32	30
Cm	96	90	80	71	62	55	50	46	42	39	35	32	30
Bk	97	91	81	72	63	5 6	51	46	43	39	36	33	30
Cf	98	92	82	73	64	57	52	47	43	40	36	33	31
	99	93	83	74	65	57	52	48	44	40	37	34	31
	100	94	84	75	66	58	53	48	44	41	37	34	31

From Peiser, Rooksby, and Wilson [G.13]. More extensive tables, at smaller intervals of $(\sin \theta)/\lambda$, are given on pp. 72–98 of Vol. 4 of [G.11].

APPENDIX 13 MULTIPLICITY FACTORS FOR THE POWDER METHOD

Cubic:	48*	$\frac{hhl}{24}$	$\frac{0kl}{24*}$	$\frac{0kk}{12}$	$\frac{hhh}{8}$	$\frac{00l}{6}$	
Hexagonal and Rhombohedral:	$\frac{hk \cdot l}{24^*}$	$\frac{hh \cdot l}{12^*}$	$\frac{0k \cdot l}{12^*}$	$\frac{hk\cdot 0}{12^*}$	$\frac{hh\cdot 0}{6}$	$\frac{0k\cdot 0}{6}$	$\frac{00 \cdot l}{2}$
Tetragonal:	hkl 16*	$\frac{hhl}{8}$	$\frac{0kl}{8}$	$\frac{hk0}{8*}$	$\frac{hh0}{4}$	$\frac{0k0}{4}$	$\frac{00l}{2}$
Orthorhombic:	$\frac{hkl}{8}$	$\frac{0kl}{4}$	$\frac{h0l}{4}$	$\frac{hk0}{4}$	$\frac{h00}{2}$	$\frac{0k0}{2}$	$\frac{00l}{2}$
Monoclinic:	$\frac{hkl}{4}$	$\frac{h0l}{2}$	$\frac{0k0}{2}$				
Triclinic:	$\frac{hkl}{2}$						

Note that, in cubic crystals, for example, *hhl* stands for such indices as 112 (or 211), 0kl for such indices as 012 (or 210), 0kk for such indices as 011 (or 110), etc.

^{*} These are the usual multiplicity factors. In some crystals, planes having these indices comprise two forms with the same spacing but different structure factor, and the multiplicity factor for each form is half the value given above. In the cubic system, for example, there are some crystals in which permutations of the indices (hkl) produce planes which are not structurally equivalent; in such crystals (AuBe, discussed in Sec. 2-7, is an example), the plane (123), for example, belongs to one form and has a certain structure factor, while the plane (321) belongs to another form and has a different structure factor. There are $\frac{48}{5} = 24$ planes in the first form and 24 planes in the second. This question is discussed more fully by Henry, Lipson, and Wooster [G.8].